

TO-92L Plastic-Encapsulate Transistors

KTA1023 TRANSISTOR (PNP)

FEATURES

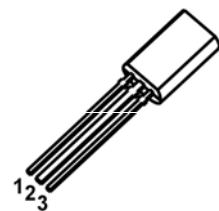
Complementary to KTC1027

MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-120	V
V_{CEO}	Collector-Emitter Voltage	-120	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_c	Collector Current -Continuous	-0.8	A
P_c	Collector Power Dissipation	1	W
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{stg}	Storage Temperature	-55 to +150	$^\circ\text{C}$

TO-92L

1. Emitter
2. Collector
3. Base



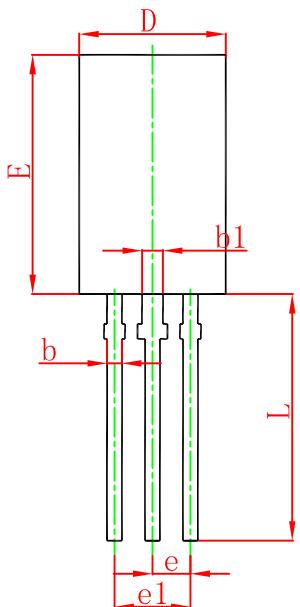
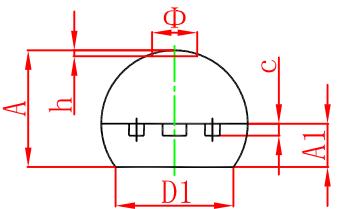
ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_c=-10\mu\text{A}, I_E=0$	-120			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_c=-10\text{mA}, I_B=0$	-120			V
Emitter-Base breakdown voltage	$V_{(BR)EBO}$	$I_E=-1\text{mA}, I_C=0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB}=-120\text{V}, I_E=0$			-0.1	μA
Emitter cut-off current	I_{EBO}	$V_{EB}=-5\text{V}, I_C=0$			-0.1	μA
DC current gain	h_{FE}	$V_{CE}=-5\text{V}, I_C=-100\text{mA}$	80		240	
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C=-500\text{mA}, I_B=-50\text{mA}$			-1.0	V
Base-emitter voltage	V_{BE}	$I_C=-500\text{mA}, V_{CE}=-5\text{V}$			-1.0	V
Transition frequency	f_T	$V_{CE}=-5\text{V}, I_C=-100\text{mA}$		120		MHz
Collector output capacitance	C_{ob}	$V_{CE}=-10\text{V}, I_E=0, f=1\text{MHz}$			40	pF

CLASSIFICATION OF h_{FE}

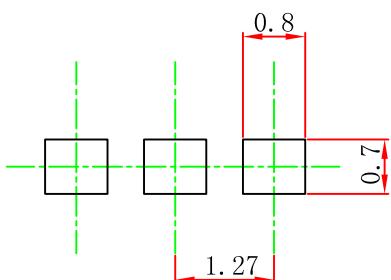
Rank	O	Y
Range	80-160	120-240

TO-92L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	3.750	4.050	0.148	0.159
A1	1.280	1.580	0.050	0.062
b	0.380	0.550	0.015	0.022
b1	0.620	0.780	0.024	0.031
c	0.350	0.450	0.014	0.018
D	4.750	5.050	0.187	0.199
D1	4.000		0.157	
E	7.850	8.150	0.309	0.321
e	1.270 TYP.		0.050 TYP.	
e1	2.440	2.640	0.096	0.104
L	13.800	14.200	0.543	0.559
Φ				
h	0.000	0.300	0.000	0.012

TO-92L Suggested Pad Layout



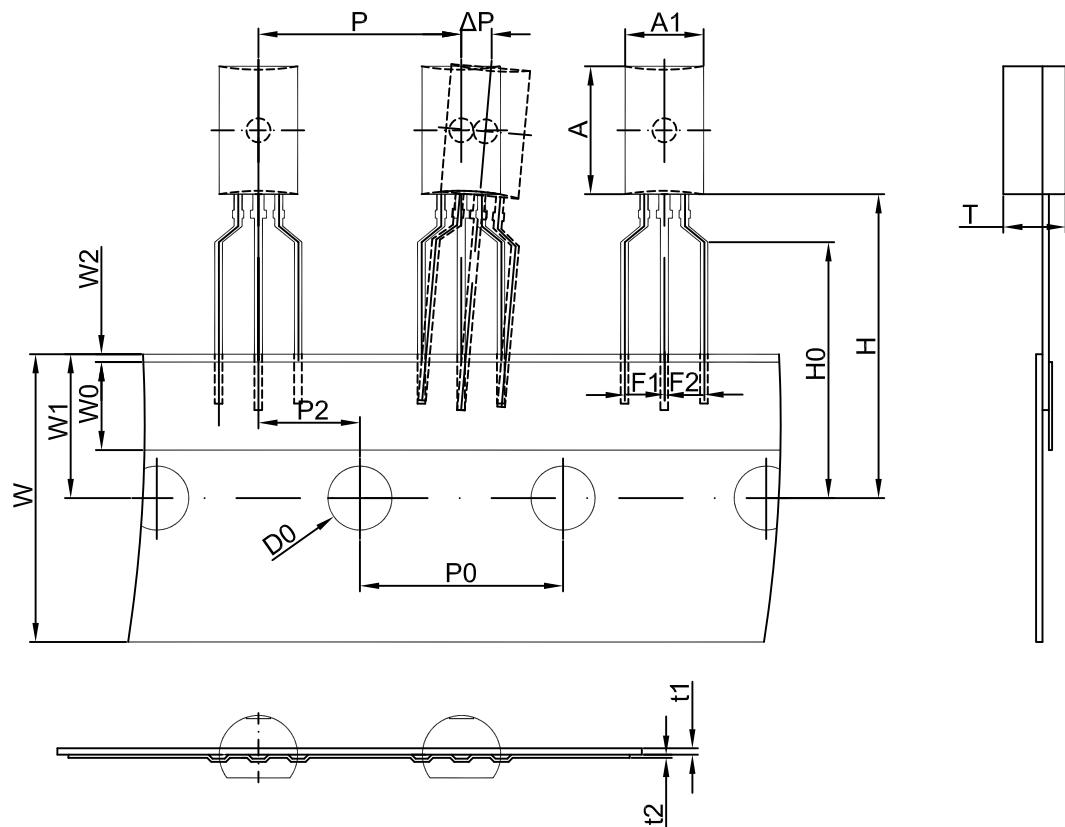
Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ± 0.05 mm.
3. The pad layout is for reference purposes only.

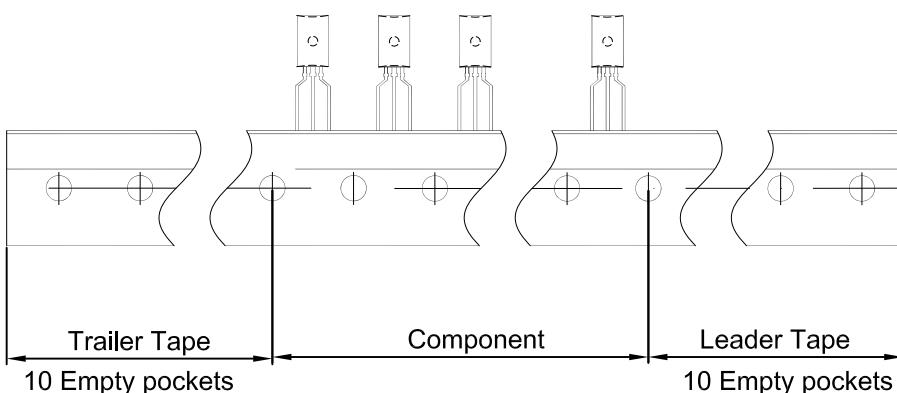
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TO-92L PACKAGE TAPEING DIMENSION



Dimensions are in millimeter								
A1	A	T	P	P0	P2	F1	F2	W
4.9±0.15	8.0±0.15	3.9±0.15	12.7±0.3	12.7±0.2	6.35±0.3	2.5±0.3	2.5±0.3	18.0+1.0/-0.5
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0±0.5	9.0±0.5	1.0 MAX.	19.0+2.0/-1.0	16.0±0.5	4.0±0.2	0.4±0.05	0.2±0.05	0 ± 1.0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92L	2000 pcs	333×203×42	20,000 pcs	493×400×264

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